MC1350P

SOUND IF AMPLIFIER





See Packaging Information Section for outline dimensions.

MC1350P (continued)

MAXIMUM RATINGS (T_A = $+25^{\circ}$ C unless otherwise noted)

Rating	Symbol	* Value	Unit
Power Supply Voltage	V+	+18	Vdc
Output Supply Voltage	V ₁ , V ₈	+18	Vdc
AGC Supply Voltage	VAGC	V+	Vdc
Differential Input Voltage	Vin	5.0	Vdc
Power Dissipation (Package Limitation)	PD		
Plastic Package		625	mW
Derate above 25 ⁰ C		5.0	mW/ ^o C
Operating Temperature Range	TA	0 to +75	°C

ELECTRICAL CHARACTERISTICS (V⁺ = +12 Vdc; $T_A = +25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
AGC Range, 45 MHz (5.0 V to 7.0 V) (Figure 1)			60	68	-	dB
Power Gain (Pin 5 grounded via a 5. f = 58 MHz, BW = 4.5 MHz f = 45 MHz, BW = 4.5 MHz f = 10.7 MHz, BW = 4.5 MHz f = 455 kHz, BW = 20 kHz	1 kΩ resistor) See Figure 5 See Figure 6	Ap	 46 -	48 50 58 62		dB
Maximum Differential Voltage Swin 0 dB AGC -30 dB AGC	9	Vo	-	20 8.0	-	V _{p-p}
Output Stage Current (Pins 1 and 8)		l ₁ +l ₈	-	5.6	-	mA
Total Supply Current (Pins 1, 2 and	8)	IS	_	14	17	mAdc
Power Dissipation		PD	-	168	204	mW

DESIGN PARAMETERS, Typical Values (V+ = +12 Vdc, T_A = +25^oC unless otherwise noted)

			Frequency			
Parameter	Symbol	455 kHz	10.7 MHz	45 MHz	58 MHz	Unit
Single-Ended Input Admittance	911 611	0.31 0.022	0.36 0.50	0.39 2.30	0.5 2.75	mmhos
Input Admittance Variations with AGC (0 to 60 dB)	Δg11 Δb11	-	_	60 0		μmhos
Differential Output Admittance	922 b22	4.0 3.0	4.4 110	30 390	60 510	μmhos
Output Admittance Variations with AGC (0 to 60 dB)	Δg ₂₂ Δb ₂₂			4.0 90	-	μmhos
Reverse Transfer Admittance (Magnitude)	V12	<< 1.0	<< 1.0	<< 1.0	<<1.0	μmho
Forward Transfer Admittence Magnitude Angle (0 dB AGC) Angle (-30 dB AGC)	V21 < V21 < V21 < V21	160 -5.0 -3.0	160 -20 -18	200 -80 -69	180 -105 -90	mmhos degræes degrees
Single-Ended Input Capacitance	C _{in}	7.2	7.2	7.4	7.6	pF
Differential Output Capacitance	Co	1.2	1.2	1.3	1.6	pF





GENERAL OPERATING INFORMATION

The input amplifiers (Q1 and Q2) operate at constant emitter currents so that input impedance remains independent of AGC action. Input signals may be applied single-ended or differentially (for ac) with identical results. Terminals 4 and 6 may be driven from a transformer, but a dc path from either terminal to ground is not permitted.

AGC action occurs as a result of an increasing voltage on the base of Q4 and Q5 causing these transistors to conduct more heavily thereby shunting signal current from the interstage amplifiers Q3 and Q6. The output amplifiers are supplied from an active current source to maintain constant quiescent bias thereby holding output admittance nearly constant. Collector voltage for the output amplifier must be supplied through a center-tapped tuning coil to Pins 1 and 8. The 12-volt supply (V⁺) at Pin 2 may be used for this purpose, but output admittance remains more nearly constant if a separate 15-volt supply (V⁺⁺) is used, because the base voltage on the output amplifier varies with AGC bias.





All power-supply chokes (L_p), are self-resonate at input frequency. L_p $\ge 20 \text{ k}\Omega$ See Figure 10 for frequency response curve.

> L 1 @ 45 MHz = 7 1/4 Turns on a 1/4" coil form. @ 58 MHz = 6 Turns on a 1/4" coil form T Primary Winding = 18 Turns on a 1/4" coil form, center-tapped Secondary Winding = 2 Turns centered over Primary Winding @ 45 MHz = 1 Turn @ 58 MHz Slug = A rould TH Material 1/2" Long

	45 MHz		58 MHz		
L	0.4 µH	0 ≥ 100	0.3 µH	0 ≥ 100	
TI	1.3 -3.4 μH	Ω ≥ 100 @ 2 μH	1.2 -3.8 μH	Ω ≥ 100 @ 2 μH	
Cl	50 - 160 pF		8	- 60 pF	
C2	8 - 60 pF		3 -	- 35 pF	



FIGURE 6 – POWER GAIN and AGC TEST CIRCUIT (455 kHz and 10.7 MHz)



Note 1. Primary: 120 µH (center-tapped) Q_u = 140 at 455 kHz Primary: Secondary turns ratio≈13

Note 2. Primary: 6.0 µH

Primary winding = 24 turns #36 AWG (close-wound on 1/4" dia. form)

Core = Arnold Type TH or equiv.

Secondary winding = 1-1/2 turns #36 AWG, 1/4" dia. (wound over center-tap)

	Frequency		
Component	455 kHz	10.7 MHz	
C1		80-450 pF	
C2	-	5.0-80 pF	
C3	0.05 µF	0.001 µF	
C4	0.05 μF	0.05 μF	
C5	0.001 µF	36 p F	
C6	0.05 μF	0.05 µF	
C7	0.05 μF	0.05 µF	
L1	-	4.6 µH	
Т1	Note 1	Note 2	





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FIGURE 11 – DIFFERENTIAL OUTPUT VOLTAGE



For additional information see "A High-Performance Monolithic IF Amplifler Incorporating Electronic Gain Control", by W. R. Davis and J. E. Solomon, IEEE Journal on Solid State Circuits, December 1968.